

## HF/VHF/UHF RF power N-channel MOSFET

Datasheet - production data

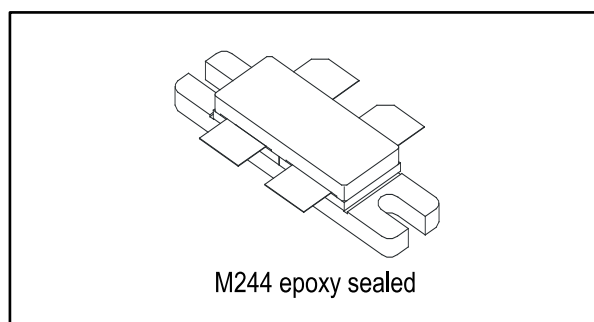
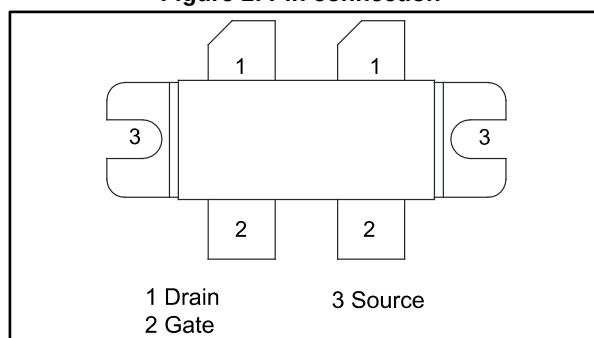


Figure 1: Pin connection



### Features

- Gold metallization
- Excellent thermal stability
- Common source push-pull configuration
- $P_{OUT} = 350\text{ W min. with } 15\text{ dB gain @ } 175\text{ MHz}$
- Low  $R_{DS(on)}$

### Description

The SD2942 is a gold metallized N-channel MOS field-effect RF power transistor. The SD2942 offers 25% lower  $R_{DS(ON)}$  than industry standard and 20% higher power saturation than ST SD2932. These characteristics make the SD2942 ideal for 50 V DC very high power applications up to 250 MHz.

Table 1: Device summary

| Order code | Marking               | Package | Packing |
|------------|-----------------------|---------|---------|
| SD2942W    | SD2942 <sup>(1)</sup> | M244    | Tube    |

#### Notes:

<sup>(1)</sup>For more details please refer to [Section 6: "Marking, packing and shipping specifications"](#).

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## Contents

|          |                                                          |           |
|----------|----------------------------------------------------------|-----------|
| <b>1</b> | <b>Electrical data .....</b>                             | <b>3</b>  |
| 1.1      | Maximum ratings .....                                    | 3         |
| 1.2      | Thermal data .....                                       | 3         |
| <b>2</b> | <b>Electrical characteristics .....</b>                  | <b>4</b>  |
| <b>3</b> | <b>Impedance data .....</b>                              | <b>5</b>  |
| <b>4</b> | <b>Typical performance .....</b>                         | <b>6</b>  |
| <b>5</b> | <b>Test circuit (175 MHz).....</b>                       | <b>10</b> |
| <b>6</b> | <b>Marking, packing and shipping specifications.....</b> | <b>13</b> |
| <b>7</b> | <b>Package information .....</b>                         | <b>14</b> |
| 7.1      | M244 package information .....                           | 14        |
| <b>8</b> | <b>Revision history .....</b>                            | <b>16</b> |

# 1 Electrical data

## 1.1 Maximum ratings

$T_{\text{CASE}} = 25\text{ °C}$

Table 2: Absolute maximum ratings

| Symbol                            | Parameter                                                 | Value       | Unit |
|-----------------------------------|-----------------------------------------------------------|-------------|------|
| $V_{(\text{BR})\text{DSS}}^{(1)}$ | Drain source voltage                                      | 130         | V    |
| $V_{\text{DGR}}$                  | Drain-gate voltage ( $R_{\text{GS}} = 1\text{ M}\Omega$ ) | 130         | V    |
| $V_{\text{GS}}$                   | Gate-source voltage                                       | $\pm 40$    | V    |
| $I_{\text{D}}$                    | Drain current                                             | 40          | A    |
| $P_{\text{DISS}}$                 | Power dissipation                                         | 500         | W    |
| $T_{\text{J}}$                    | Max. operating junction temperature                       | +200        | °C   |
| $T_{\text{STG}}$                  | Storage temperature                                       | -65 to +150 | °C   |

**Notes:**

<sup>(1)</sup> $T_{\text{J}} = 150\text{ °C}$

## 1.2 Thermal data

Table 3: Thermal data

| Symbol            | Parameter                           | Value | Unit |
|-------------------|-------------------------------------|-------|------|
| $R_{\text{thJC}}$ | Junction-to-case thermal resistance | 0.35  | °C/W |

## 2 Electrical characteristics

$T_{CASE} = 25\text{ }^{\circ}\text{C}$

**Table 4: Static**

| Symbol              | Test conditions        |                          | Min. | Typ. | Max. | Unit          |
|---------------------|------------------------|--------------------------|------|------|------|---------------|
| $V_{(BR)DSS}^{(1)}$ | $V_{GS} = 0\text{ V}$  | $I_{DS} = 100\text{ mA}$ | 130  |      |      | V             |
| $I_{DSS}$           | $V_{GS} = 0\text{ V}$  | $V_{DS} = 50\text{ V}$   |      |      | 100  | $\mu\text{A}$ |
| $I_{GSS}$           | $V_{GS} = 20\text{ V}$ | $V_{DS} = 0\text{ V}$    |      |      | 250  | nA            |
| $V_{GS(Q)}$         | $V_{DS} = 10\text{ V}$ | $I_D = 250\text{ mA}$    | 1.5  |      | 4    | V             |
| $V_{DS(ON)}$        | $V_{GS} = 10\text{ V}$ | $I_D = 10\text{ A}$      |      |      | 3.0  | V             |
| $G_{FS}$            | $V_{DS} = 10\text{ V}$ | $I_D = 5\text{ A}$       | 5    |      |      | mho           |
| $C_{ISS}$           | $V_{GS} = 0\text{ V}$  | $V_{DS} = 50\text{ V}$   |      | 415  |      | pF            |
| $C_{OSS}$           | $V_{GS} = 0\text{ V}$  | $V_{DS} = 50\text{ V}$   |      | 236  |      | pF            |
| $C_{RSS}$           | $V_{GS} = 0\text{ V}$  | $V_{DS} = 50\text{ V}$   |      | 17   |      | pF            |

**Notes:**

<sup>(1)</sup> $T_J = 150\text{ }^{\circ}\text{C}$

**Table 5: Dynamic**

| Symbol        | Test conditions        |                                                                                               | Min. | Typ. | Max. | Unit |
|---------------|------------------------|-----------------------------------------------------------------------------------------------|------|------|------|------|
| $P_{OUT}$     | $V_{DD} = 50\text{ V}$ | $I_{DQ} = 500\text{ mA}$ $f = 175\text{ MHz}$                                                 | 350  |      |      | W    |
| $G_{PS}$      | $V_{DD} = 50\text{ V}$ | $I_{DQ} = 500\text{ mA}$ $P_{OUT} = 350\text{ W}$<br>$f = 175\text{ MHz}$                     | 15   | 17   |      | dB   |
| $\eta_D$      | $V_{DD} = 50\text{ V}$ | $I_{DQ} = 500\text{ mA}$ $P_{OUT} = 350\text{ W}$<br>$f = 175\text{ MHz}$                     | 55   | 61   |      | %    |
| Load mismatch | $V_{DD} = 50\text{ V}$ | $I_{DQ} = 500\text{ mA}$ $P_{OUT} = 350\text{ W}$<br>$f = 175\text{ MHz}$<br>All phase angles | 5:1  |      |      | VSWR |

### 3 Impedance data

Figure 2: Impedance data

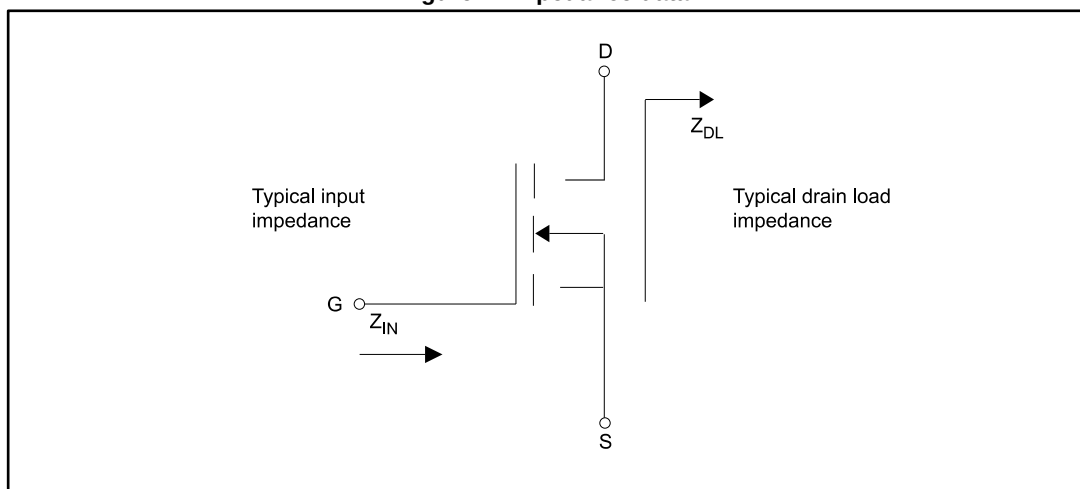


Table 6: Impedance data

| f       | $Z_{IN}(\Omega)$ | $Z_{DL}(\Omega)$ |
|---------|------------------|------------------|
| 250 MHz | 1.3 - j 1.9      | 1.9 + j 3.2      |
| 230 MHz | 1.2 - j 1.8      | 2.1 + j 3.7      |
| 200 MHz | 1.1 - j 1.6      | 2.7 + j 4.2      |
| 175 MHz | 1.0 - j 1.4      | 3.3 + j 4.8      |
| 100 MHz | 1.8 - j 2.5      | 7.5 + j 9        |
| 50 MHz  | 3.2 - j 4.4      | 10 + j 12        |

## 4 Typical performance

Figure 3: Capacitance vs. drain voltage

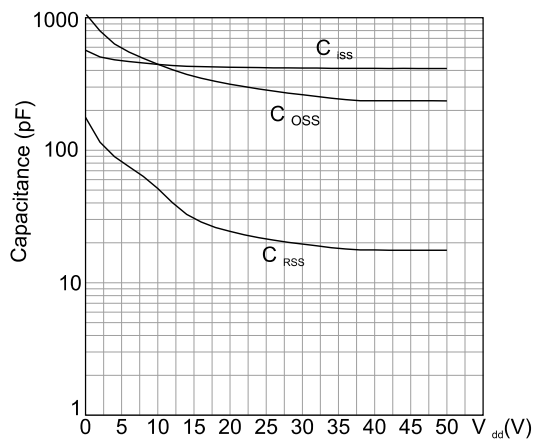


Figure 4: Drain current vs. gate voltage

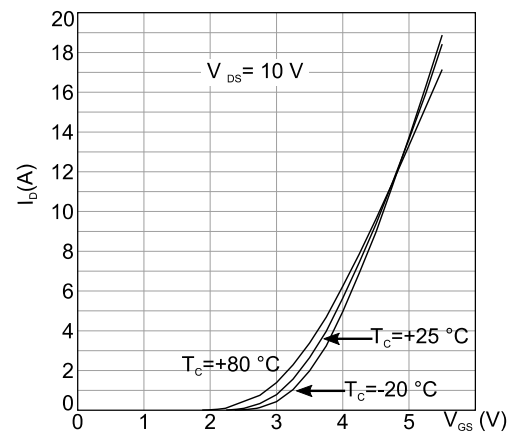


Figure 5: Gate-source voltage vs. case temperature

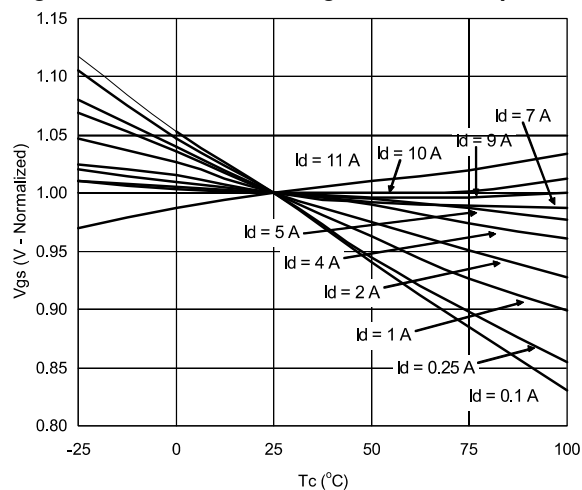


Figure 6: Power gain vs. POUT and case temperature

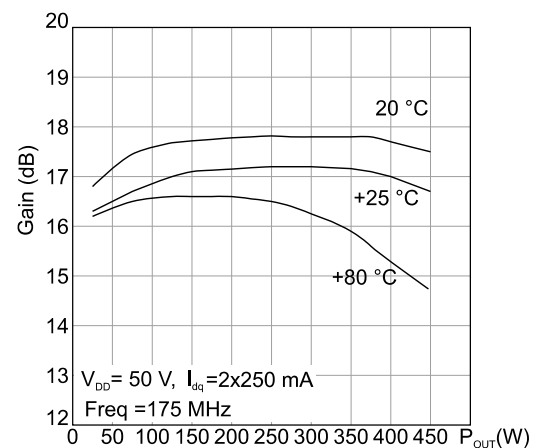


Figure 7: Efficiency vs. case temperature

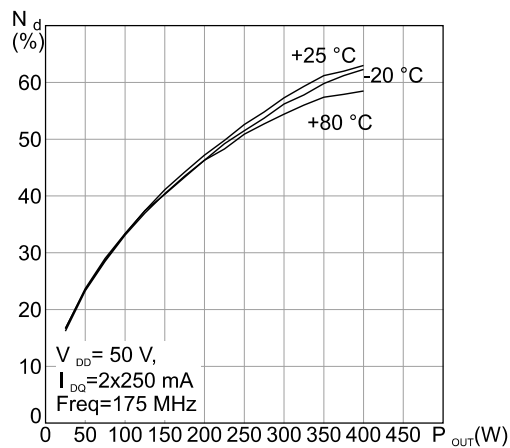
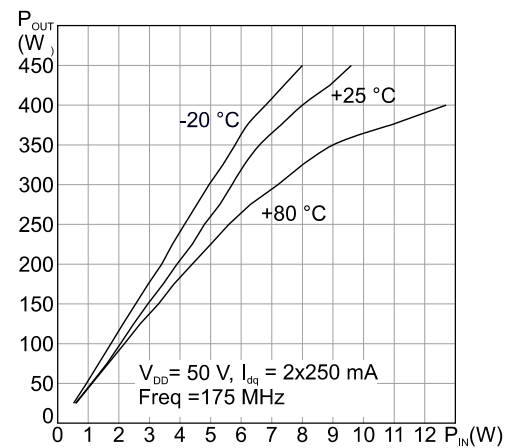
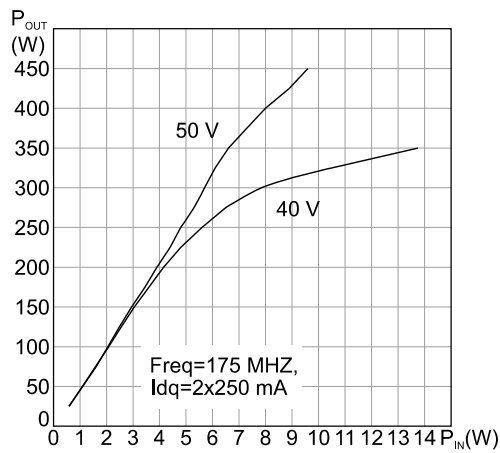
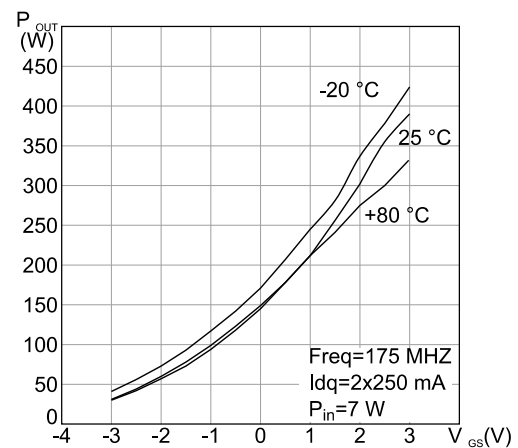
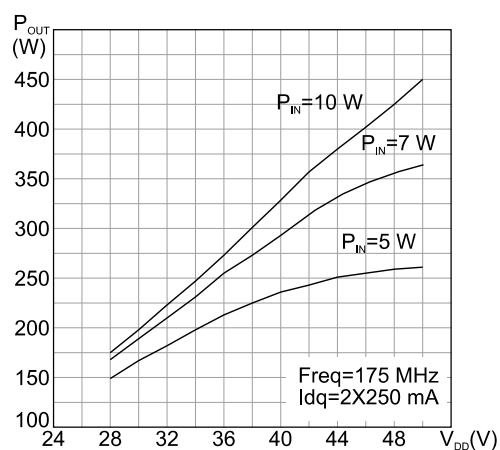
Figure 8:  $P_{OUT}$  vs. input power and case temperatureFigure 9:  $P_{OUT}$  vs. input power and drain voltageFigure 10:  $P_{OUT}$  vs. gate voltage and case temperatureFigure 11:  $P_{OUT}$  vs. drain voltage and input power

Figure 12: Maximum thermal resist vs. case temperature

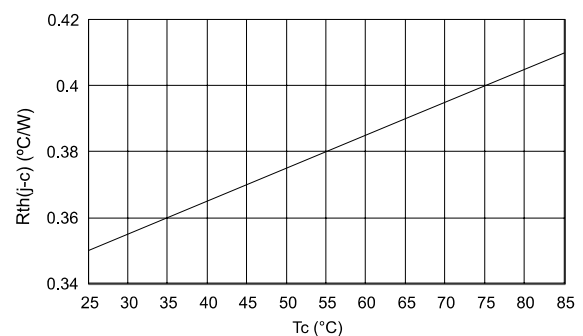


Figure 13: Maximum safe operating area

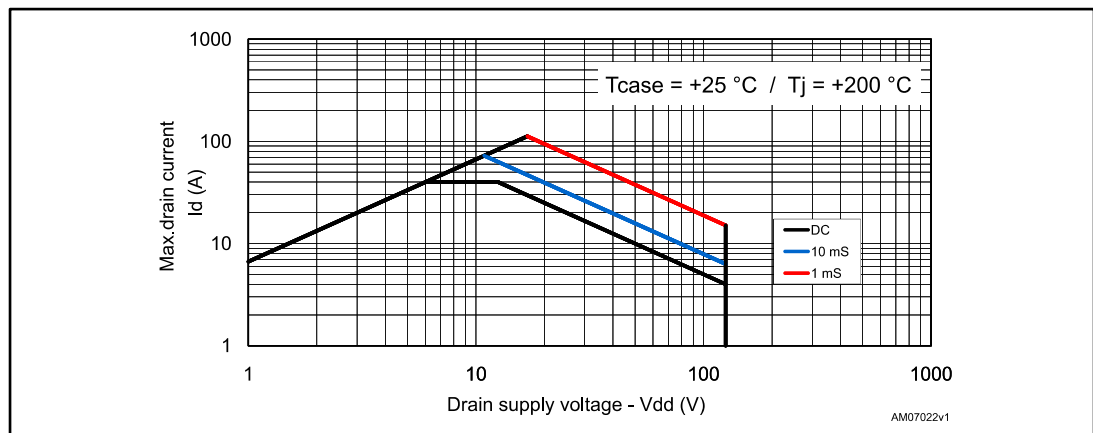


Figure 14: Transient thermal impedance

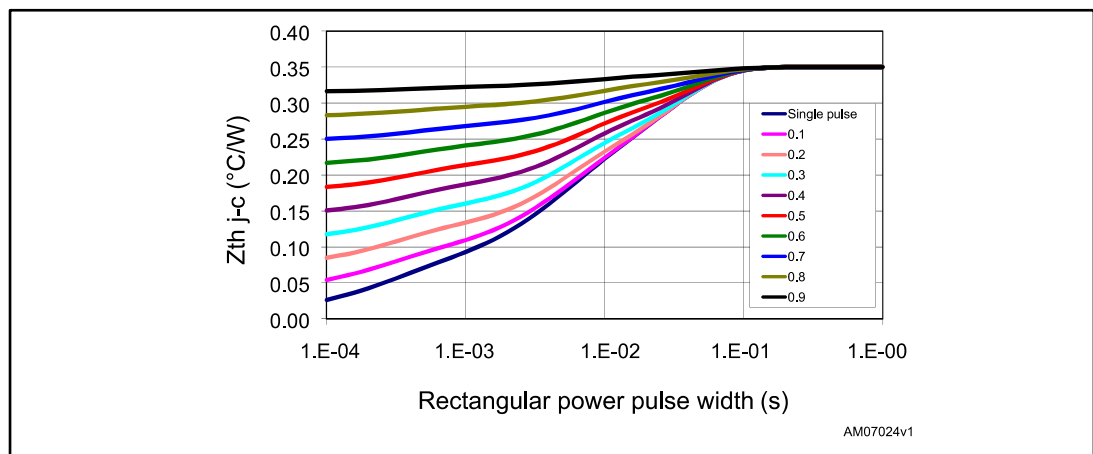
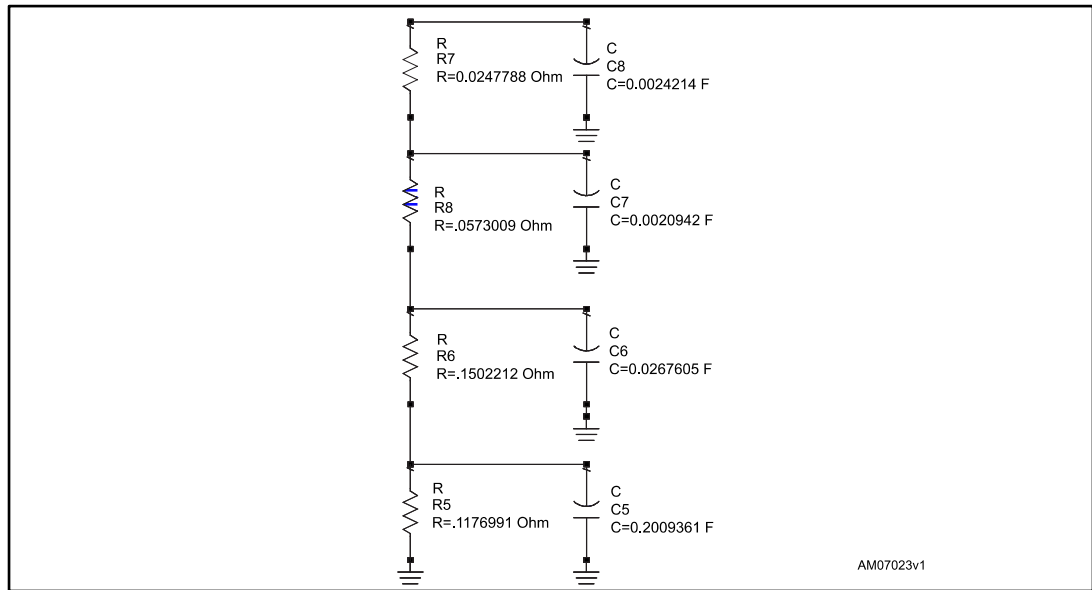


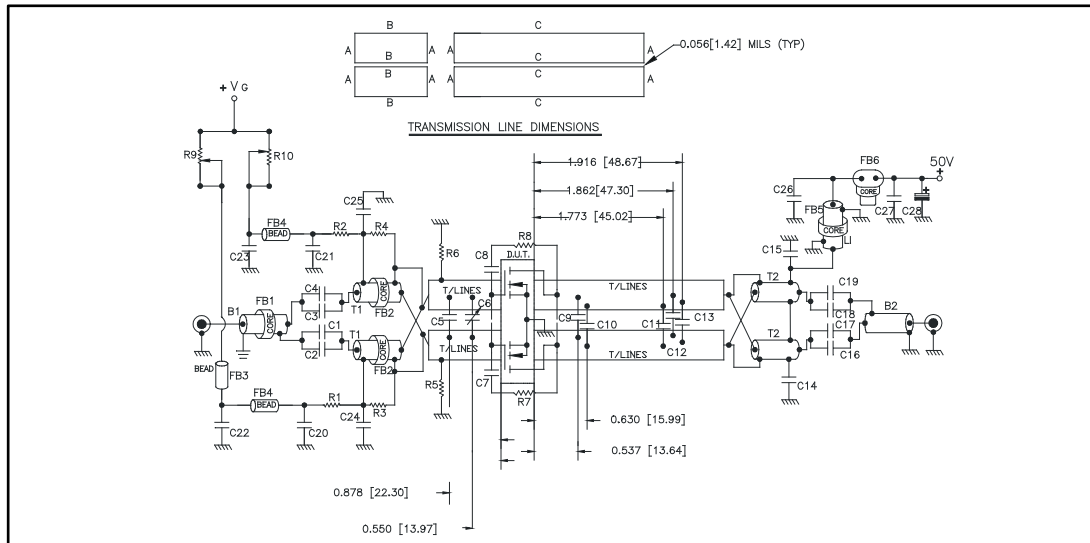


Figure 15: Transient thermal model



## 5 Test circuit (175 MHz)

Figure 16: 175 MHz production test circuit schematic



Dimensions at component symbols are references for component placement. Gap between ground and transmission lines is + 0.002{0.05} - 0.000{0.00} typ.

Table 7: 175 MHz test circuit part list

| Component                          | Description                                                     |
|------------------------------------|-----------------------------------------------------------------|
| R1, R2, R5, R6                     | 470 Ohm 1 W, surface mount chip resistor                        |
| R3, R4                             | 360 Ohm 0.5 W, carbon comp. axial lead resistor or equivalent   |
| R7, R8                             | 560 Ohm 2 W, resistor 2 turn wire air-wound axial lead resistor |
| R9, R10                            | 20 kOhm 3.09 W, 10 turn wirewound precision potentiometer       |
| C1, C4                             | 680 pF ATC 130B surface mount ceramic chip capacitor            |
| C2, C3, C7, C8, C17, C19, C20, C21 | 10000 pF ATC 200B surface mount ceramic chip capacitor          |
| C5                                 | 75 pF ATC 100B surface mount ceramic chip capacitor             |
| C6                                 | ST40 25 pF - 115 pF miniature variable trimmer                  |
| C9, C10                            | 47 pF ATC 100B surface mount ceramic chip capacitor             |
| C11, C12, C13                      | 43 pF ATC 100B surface mount ceramic chip capacitor             |
| C14, C15, C24, C25                 | 1200 pF ATC 700B surface mount ceramic chip capacitor           |
| C16, C18                           | 470 pF ATC 700B surface mount ceramic chip capacitor            |
| C22, C23                           | 0.1 $\mu$ F / 500 V surface mount ceramic chip capacitor        |
| C26, C27                           | 0.01 $\mu$ F / 500 V surface mount ceramic chip capacitor       |
| C28                                | 10 $\mu$ F / 63 aluminum electrolytic axial lead capacitor      |

| Component | Description                                                                                                                                      |
|-----------|--------------------------------------------------------------------------------------------------------------------------------------------------|
| B1        | 50 Ohm RG316 O.D 0.076[1.93] L = 11.80[299.72] flexible coaxial cable 4 turns through ferrite bead                                               |
| B2        | 50 Ohm RG-142B O.D 0.165[4.19] L = 11.80[299.72] flexible coaxial cable                                                                          |
| T1        | R.F. transformer 4:1, 25 Ohm O.D RG316-25 O.D 0.080[2.03]<br>L = 5.90[149.86] flexible coaxial cable 2 turns through ferrite multi-aperture core |
| T2        | R.F. transformer 1:4, 25 Ohm semi-rigid coaxial cable O.D. 0.141[3.58]<br>L = 5.90[149.86]                                                       |
| L1        | Inductor $\lambda$ 1/4 wave 50 Ohm O.D 0.165[4.19] L = 11.80 [299.72] flexible coaxial cable 2 turns through ferrite bead                        |
| FB1, FB5  | Shield bead                                                                                                                                      |
| FB2, FB6  | Multi-aperture core                                                                                                                              |
| FB3       | Multilayer ferrite chip bead (surface mount)                                                                                                     |
| FB4       | Surface mount EMI shield bead                                                                                                                    |
| PCB       | Woven glass reinforced PTFE microwave laminate 0.06", 1 oz EDCu, both sides, $\epsilon_r = 2.55$                                                 |

Figure 17: 175 MHz test circuit photomaster

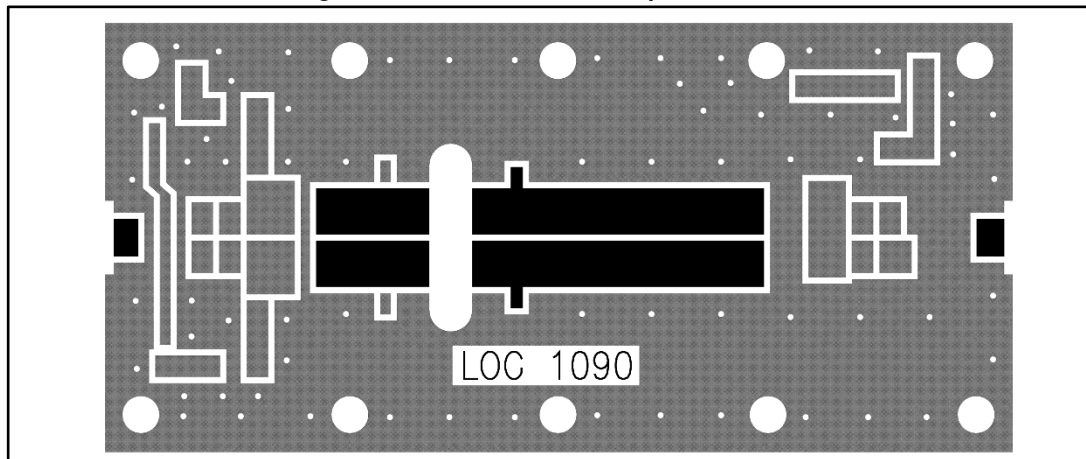
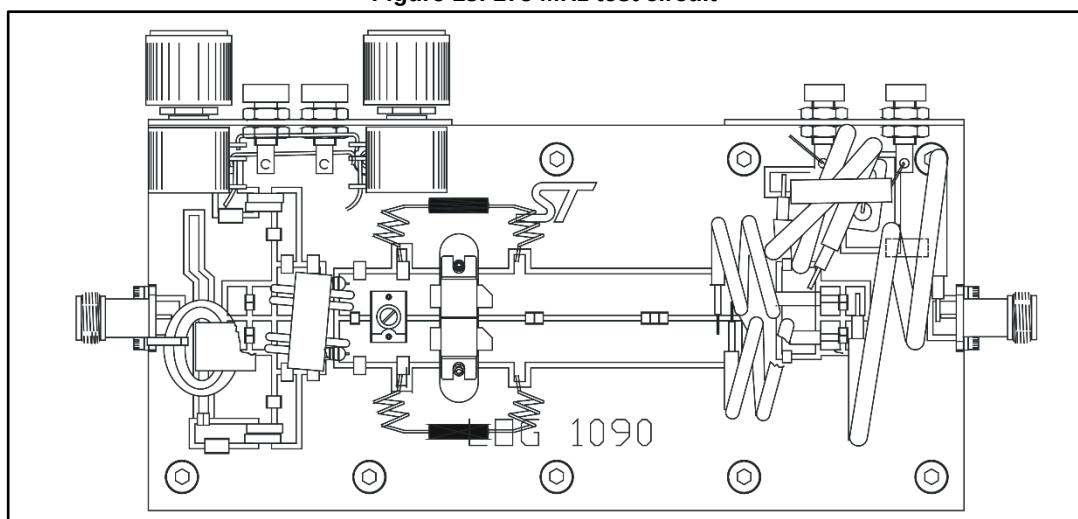


Figure 18: 175 MHz test circuit



## 6 Marking, packing and shipping specifications

Table 8: Packing and shipping specifications

| Order code | Packing | Pieces per tray | Dry pack humidity | Lot code  |
|------------|---------|-----------------|-------------------|-----------|
| SD2942W    | Tube    | 15              | < 10%             | Not mixed |

Figure 19: SD2942 marking layout

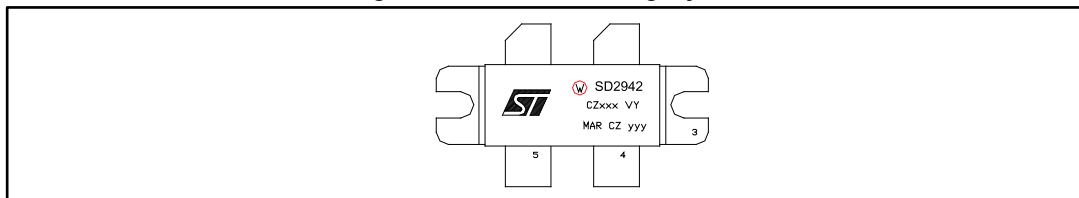


Table 9: Marking specifications

| Symbol | Description                    |
|--------|--------------------------------|
| W      | Wafer process code             |
| CZ     | Assembly plant                 |
| xxx    | Last 3 digits of diffusion lot |
| VY     | Diffusion plant                |
| MAR    | Country of origin              |
| CZ     | Test and finishing plant       |
| y      | Assembly year                  |
| yy     | Assembly week                  |

## 7 Package information

In order to meet environmental requirements, ST offers these devices in different grades of ECOPACK® packages, depending on their level of environmental compliance. ECOPACK® specifications, grade definitions and product status are available at: [www.st.com](http://www.st.com). ECOPACK® is an ST trademark.

### 7.1 M244 package information

Figure 20: M244 (0.400 x .860 4L BAL N/HERM W/FLG) package outline

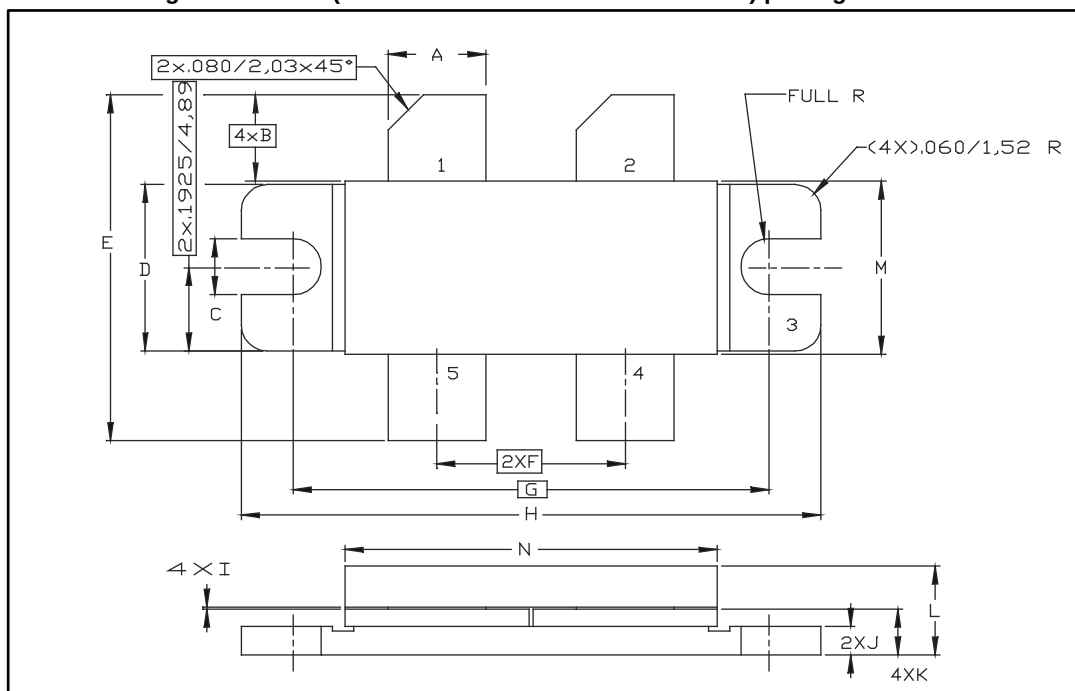


Table 10: M244 (0.400 x .860 4L BAL N/HERM W/FLG) package mechanical data

| Dim. | mm    |       |       |
|------|-------|-------|-------|
|      | Min.  | Typ.  | Max.  |
| A    | 5.59  |       | 5.84  |
| B    |       | 5.08  |       |
| C    | 3.02  |       | 3.28  |
| D    | 9.65  |       | 9.91  |
| E    | 19.81 |       | 20.82 |
| F    | 10.92 |       | 11.18 |
| G    |       | 27.94 |       |
| H    | 33.91 |       | 34.16 |
| I    | 0.10  |       | 0.15  |
| J    | 1.52  |       | 1.78  |
| K    | 2.59  |       | 2.84  |
| L    | 4.83  |       | 5.84  |
| M    | 10.03 |       | 10.34 |
| N    | 21.59 |       | 22.10 |

## 8 Revision history

Table 11: Document revision history

| Date        | Revision | Changes                                                                   |
|-------------|----------|---------------------------------------------------------------------------|
| 18-Oct-2005 | 1        | First issue.                                                              |
| 04-Jan-2006 | 2        | Complete version.                                                         |
| 14-Apr-2010 | 3        | Added <i>Figure 13</i> , <i>Figure 14</i> and <i>Figure 15</i> .          |
| 25-Oct-2011 | 4        | Inserted <i>Chapter 7: Marking, packing and shipping specifications</i> . |
| 24-Nov-2016 | 5        | Updated <a href="#">Table 2: "Absolute maximum ratings"</a> .             |



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